

LM75B

LM75C Digital Temperature Sensor and Thermal Watchdog with Two-Wire Interface

Check for Samples: LM75B, LM75C

FEATURES

- **No External Components Required**
- **Shutdown Mode to Minimize Power** Consumption
- Up to Eight LM75s Can be Connected to a Single Bus
- **Power Up Defaults Permit Stand-alone Operation as Thermostat**
- **UL Recognized Component (LM75B and** LM75C) **%**

APPLICATIONS

- **General System Thermal Management**
- **Communications Infrastructure**
- **Electronic Test Equipment**
- **Environmental Monitoring**

KEY SPECIFICATIONS

Supply Voltage

- LM75B, LM75C: 3.0V to 5.5V

Supply Current

Operating: 280 μA (typ) Shutdown: 4 μA (typ)

Temperature Accuracy

- 25°C to 100°C: ±2°C (max) -55°C to 125°C: ±3°C (max)

DESCRIPTION

The LM75B and LM75C are industy-standard digital temperature sensors with an integrated Sigma-Delta analog-to-digital converter and I2C interface. The LM75 provides 9-bit digital temperature readings with an accuracy of ±2°C from -25°C to 100°C and ±3°C over -55°C to 125°C.

Communication is accomplished over a 2-wire interface which operates up to 400kHz. The LM75 has three address pins, allowing up to eight LM75 devices to operate on the same 2-wire bus. The LM75 has a dedicated over-temperature output (O.S.) with programmable limit and hystersis. This output has programmable fault tolerance, which allows the user to define the number of consecutive error conditions that must occur before O.S. is activated.

The wide temperature and supply range and I²C interface make the LM75 ideal for a number of applications including base stations, electronic test equipment, office electronics, personal computers, and any other system where thermal management is critical to performance. The LM75B and LM75C are available in an SOIC package or VSSOP package.

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Simplified Block Diagram

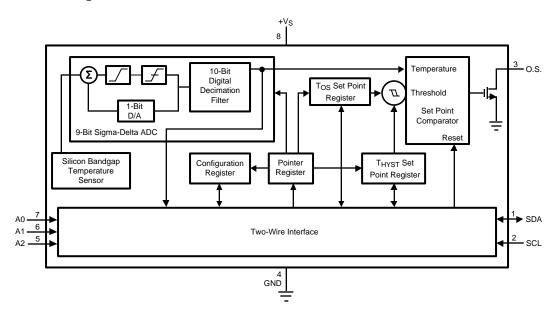
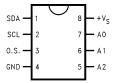


Figure 1.

Connection Diagram



LM75B, LM75C, SOIC and VSSOP

PIN DESCRIPTIONS

Label	Pin #	Function	Typical Connection
SDA	1	I ² C Serial Bi-Directional Data Line. Open Drain.	From Controller, tied to a pull-up resistor or current source
SCL	2	I ² C Clock Input	From Controller, tied to a pull-up resistor or current source
O.S.	3	Over temperature Shutdown. Open Drain Output	Pull-up Resistor, Controller Interrupt Line
GND	4	Power Supply Ground	Ground
+V _S	8	Positive Supply Voltage Input	DC Voltage from 3V to 5.5V; 100 nF bypass capacitor with 10 μ F bulk capacitance in the near vicinity
A0-A2	7,6,5	User-Set I ² C Address Inputs	Ground (Low, "0") or +V _S (High, "1")



Typical Application

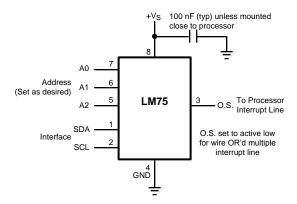


Figure 2. Typical Application



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings(1)

J 3			
		-0.3V to 6.5V	
		-0.3V to (+V _S + 0.3V) and must be ≤ 6.5V	
Voltage at OS, SCL and SDA Pins			
		5 mA	
		20 mA	
		−65°C to +150°C	
Liverage Dady Madal	LM75B	2500V	
Human Body Model	LM75C	1500V	
Manhina Manlal	LM75B	250V	
Machine Model	LM75C	100V	
		10 mA	
		6.5V	
	Human Body Model Machine Model	Human Body Model LM75B LM75C LM75B Machine Model	

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. DC and AC electrical specifications do not apply when operating the device beyond its rated operating conditions.
- (2) When the input voltage (V_I) at any pin exceeds the power supplies (V_I < GND or V_I > +V_S) the current at that pin should be limited to 5 mA. The 20 mA maximum package input current rating limits the number of pins that can safely exceed the power supplies with an input current of 5 mA to four.
- (3) Human body model, 100 pF discharged through a 1.5 kΩ resistor. Machine model, 200 pF discharged directly into each pin. The Charged Device Model (CDM) is a specified circuit characterizing an ESD event that occurs when a device acquires charge through some triboelectric (frictional) or electrostatic induction processes and then abruptly touches a grounded object or surface.

Operating Ratings⁽¹⁾⁽²⁾

Specified Temperature Range	T _{MIN} to T _{MAX}
See ⁽³⁾	−55°C to +125°C
Supply Voltage Range (+V _S) LM75B, LM75C	+3.0V to +5.5V

- (1) Soldering process must comply with Texas Instruments Incorporated Reflow Temperature Profile specifications. Refer to
- 2) Reflow temperature profiles are different for lead-free and non-lead-free packages.
- (3) LM75 θ_{JA} (thermal resistance, junction-to-ambient) when attached to a printed circuit board with 2 oz. foil similar to the one shown in Figure 5 is summarized in the table below:



Device Number	Package Number	Thermal Resistance (θ _{JA})
LM75BIM-3, LM75BIM-5, LM75CIM-3, LM75CIM-5	D (R-PDSO-G8)	200°C/W
LM75BIMM-3, LM75BIMM-5, LM75CIMM-3, LM75CIMM-5	DGK (S-PDSO- G8)	250°C/W

Temperature-to-Digital Converter Characteristics⁽¹⁾

Unless otherwise noted, these specifications apply for: $+V_S = +5$ Vdc for LM75BIM-5, LM75BIMM-5, LM75CIM-5, and LM75CIMM-5; and $+V_S = +3.3$ Vdc for LM75BIM-3, LM75BIMM-3, LM75CIM-3, and LM75CIMM- $3^{(2)}$. **Boldface limits apply for T_A = T_J = T_{MIN} to T_{MAX}**; all other limits T_A = T_J = $+25^{\circ}$ C, unless otherwise noted.

Parameter	r	Conditions	Typical ⁽³⁾	Limits ⁽⁴⁾	Units (Limit)
A	Accuracy			±2.0	°C ()
Resolution Temperature Conversion Time		$T_A = -55^{\circ}C \text{ to } +125^{\circ}C$		±3.0	°C (max)
			9		Bits
		See ⁽⁵⁾	100	300	ms (max)
		I ² C Inactive	0.25	0.5	mA (max)
Quiescent Current	LM75B	Shutdown Mode, +V _S = 3V	4		^
		Shutdown Mode, $+V_S = 5V$	6		μΑ
		I ² C Inactive	0.25	1.0	mA (max)
	LM75C	Shutdown Mode, $+V_S = 3V$	4		^
		Shutdown Mode, +V _S = 5V	6		μΑ
O.S. Output Saturation Voltage	je	I _{OUT} = 4.0 mA		0.8	V (max)
O.S. Delay				⁽⁶⁾ 1	Conversion (min)
				6	Conversions (max)
T _{OS} Default Temperature T _{HYST} Default Temperature		2 (7)	80		00
		See ⁽⁷⁾	75		°C

- (1) For best accuracy, minimize output loading. Higher sink currents can affect sensor accuracy with internal heating. This can cause an error of 0.64°C at full rated sink current and saturation voltage based on junction-to-ambient thermal resistance.
- (2) All part numbers of the LM75 will operate properly over the +V_S supply voltage range of 3V to 5.5V. The devices are tested and specified for rated accuracy at their nominal supply voltage. Accuracy will typically degrade 1°C/V of variation in +V_S as it varies from the nominal value.
- (3) Typicals are at $T_A = 25^{\circ}C$ and represent most likely parametric norm.
- (4) Limits are specified to AOQL (Average Outgoing Quality Level).
- (5) The conversion-time specification is provided to indicate how often the temperature data is updated. The LM75 can be accessed at any time and reading the Temperature Register will yield result from the last temperature conversion. When the LM75 is accessed, the conversion that is in process will be interrupted and it will be restarted after the end of the communication. Accessing the LM75 continuously without waiting at least one conversion time between communications will prevent the device from updating the Temperature Register with a new temperature conversion result. Consequently, the LM75 should not be accessed continuously with a wait time of less than 300 ms.

- (6) O.S. Delay is user programmable up to 6 "over limit" conversions before O.S. is set to minimize false tripping in noisy environments.
- (7) Default values set at power up.



Logic Electrical Characteristics

DIGITAL DC CHARACTERISTICS

Unless otherwise noted, these specifications apply for $+V_S = +5$ Vdc for LM75BIM-5, LM75BIMM-5, LM75CIM-5, and LM75CIMM-5; and $+V_S = +3.3$ Vdc for LM75BIM-3, LM75BIMM-3, LM75CIM-3, and LM75CIMM-3⁽¹⁾. **Boldface limits apply for T_A = T_J = T_{MIN} to T_{MAX}**; all other limits T_A = T_J = $+25^{\circ}$ C, unless otherwise noted.

Symbol	Parameter		Conditions	Typical ⁽²⁾	Limits ⁽³⁾	Units (Limit)	
\ /	Lariad #4" Innut Valtana				+V _S × 0.7	V (min)	
$V_{IN(1)}$	Logical "1" Input Voltage			+V _S + 0.3	V (max)		
\ /	Larias ("O" Innut Valtana				-0.3	V (min)	
$V_{IN(0)}$	Logical "0" Input Voltage				+V _S × 0.3	V (max)	
I _{IN(1)}	Logical "1" Input Current		$V_{IN} = +V_{S}$	0.005	1.0	μA (max)	
I _{IN(0)}	Logical "0" Input Current		$V_{IN} = 0V$	-0.005	-1.0	μA (max)	
C _{IN}	All Digital Inputs			5		pF	
	High Lovel Output Current	LM75B	V _{OH} = 5V		10	μA (max)	
I _{OH}	High Level Output Current	LM75C	V _{OH} = 5V		100	μA (max)	
V _{OL}	Low Level Output Voltage		I _{OL} = 3 mA		0.4	V (max)	
t _{OF}	Output Fall Time		$C_L = 400 \text{ pF I}_O = 3 \text{ mA}$		250	ns (max)	

⁽¹⁾ All part numbers of the LM75 will operate properly over the +V_S supply voltage range of 3V to 5.5V. The devices are tested and specified for rated accuracy at their nominal supply voltage. Accuracy will typically degrade 1°C/V of variation in +V_S as it varies from the nominal value.

Logic Electrical Characteristics

I²C Digital Switching Characteristics

Unless otherwise noted, these specifications apply for $V_S = +5$ Vdc for LM75BIM-5, LM75BIMM-5, LM75CIM-5, and LM75CIMM-5; and $+V_S = +3.3$ Vdc for LM75BIM-3, LM75BIMM-3, LM75CIM-3, and LM75CIMM-3C_L (load capacitance) on output lines = 80 pF unless otherwise specified. **Boldface limits apply for T_A = T_J = T_{MIN} to T_{MAX}**; all other limits T_A = T_J = $+25^{\circ}$ C, unless otherwise noted.

Symbol	Parameter	Conditions	Typical ⁽¹⁾	Limits ⁽²⁾⁽³⁾	Units (Limit)	
t ₁	SCL (Clock) Period			2.5	μs (min)	
t ₂	Data in Set-Up Time to SCL High			100	ns (min)	
t ₃	Data Out Stable after SCL Low			0	ns (min)	
t ₄	SDA Low Set-Up Time to SCL Low (Start Condition)			100	ns (min)	
t ₅	SDA High Hold Time after SCL High (Stop Condition)			100	ns (min)	
t _{TIMEOUT}	SDA Time Low for Reset of Serial Interface (4)	LM75B			75 325	ms (min) ms (max)
TIMEGOT				Not App	licable	

⁽¹⁾ Typicals are at $T_A = 25^{\circ}C$ and represent most likely parametric norm.

⁽²⁾ Typicals are at $T_A = 25$ °C and represent most likely parametric norm.

⁽³⁾ Limits are specified to AOQL (Average Outgoing Quality Level).

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⁽³⁾ Timing specifications are tested at the bus input logic levels (Vin(0)=0.3xVA for a falling edge and Vin(1)=0.7xVA for a rising edge) when the SCL and SDA edge rates are similar.

⁽⁴⁾ Holding the SDA line low for a time greater than t_{TIMEOUT} will cause the LM75B to reset SDA to the IDLE state of the serial bus communication (SDA set High).



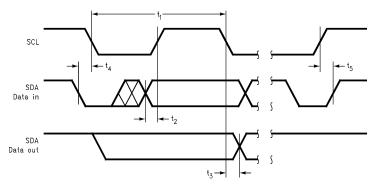


Figure 3.

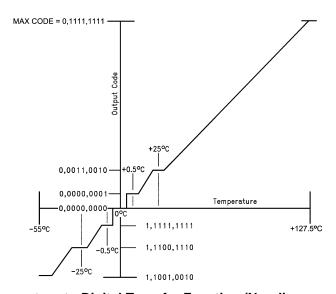


Figure 4. Temperature-to-Digital Transfer Function (Non-linear scale for clarity)

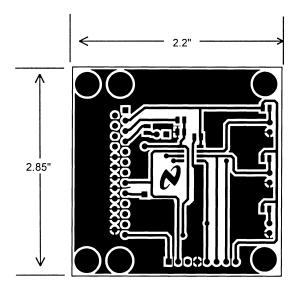


Figure 5. Printed Circuit Board Used for Thermal Resistance Specifications



TYPICAL PERFORMANCE CHARACTERISTICS

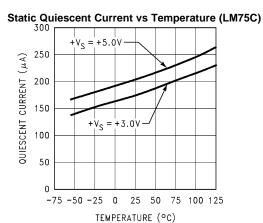
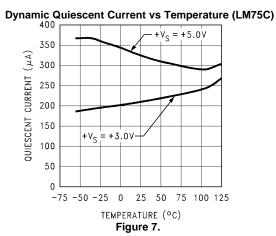
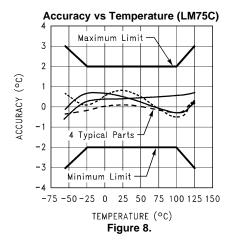


Figure 6.







FUNCTIONAL DESCRIPTION

The LM75 temperature sensor incorporates a band-gap type temperature sensor and 9-bit ADC (Sigma-Delta Analog-to-Digital Converter). The temperature data output of the LM75 is available at all times via the I²C bus. If a conversion is in progress, it will be stopped and restarted after the read. A digital comparator is also incorporated that compares a series of readings, the number of which is user-selectable, to user-programmable setpoint and hysteresis values. The comparator trips the O.S. output line, which is programmable for mode and polarity.

The LM75B contains all the functionality of the LM75C, plus two additional features:

- 1. The LM75B has an integrated low-pass filter on both the SDA and the SCL line. These filters increase communications reliability in noisy environments.
- The LM75B also has a bus fault timeout feature. If the SDA line is held low for longer than t_{TIMEOUT} (see Logic Electrical Characteristics) the LM75B will reset to the IDLE state (SDA set to high impedance) and wait for a new start condition. The TIMEOUT feature is not functional in Shutdown Mode.

O.S. OUTPUT, T_{OS} AND T_{HYST} LIMITS

In Comparator mode the O.S. Output behaves like a thermostat. The output becomes active when temperature exceeds the T_{OS} limit, and leaves the active state when the temperature drops below the T_{HYST} limit. In this mode the O.S. output can be used to turn a cooling fan on, initiate an emergency system shutdown, or reduce system clock speed. Shutdown mode does not reset O.S. state in a comparator mode.

In Interrupt mode exceeding T_{OS} also makes O.S. active but O.S. will remain active indefinitely until reset by reading any register via the I^2C interface. Once O.S. has been activated by crossing T_{OS} , then reset, it can be activated again only by Temperature going below T_{HYST} . Again, it will remain active indefinitely until being reset by a read. Placing the LM75 in shutdown mode also resets the O.S. Output.

POWER UP AND POWER DOWN

The LM75 always powers up in a known state. The power up default conditions are:

- 1. Comparator mode
- 2. $T_{OS} = 80^{\circ}C$
- 3. $T_{HYST} = 75^{\circ}C$
- 4. O.S. active low
- 5. Pointer = "00"

When the supply voltage is less than about 1.7V, the LM75 is considered powered down. As the supply voltage rises above the nominal 1.7V power up threshold, the internal registers are reset to the power up default values listed above.

Stand-Alone Thermostat Mode

If the LM75 is *not connected* to the I²C bus on power up, it will act as a stand-alone thermostat with the power up default conditions listed above. It is optional, but recommended, to connect the address pins (A2, A1, A0) and the SCL and SDA pins together and to a 10k pull-up resistor to +V_S for better noise immunity. Any of these pins may also be tied high separately through a 10k pull-up resistor.

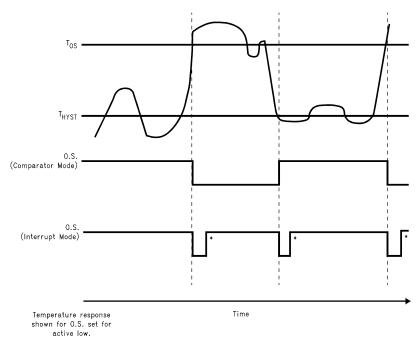
I²C BUS INTERFACE

The LM75 operates as a slave on the I^2C bus, so the SCL line is an input (no clock is generated by the LM75) and the SDA line is a bi-directional serial data path. According to I^2C bus specifications, the LM75 has a 7-bit slave address. The four most significant bits of the slave address are hard wired inside the LM75 and are "1001". The three least significant bits of the address are assigned to pins A2–A0, and are set by connecting these pins to ground for a low, (0); or to $+V_S$ for a high, (1).

Therefore, the complete slave address is:

1	0	0	1	A2	A1	A0
MSB	•					LSB





These interrupt mode resets of O.S. occur only when LM75 is read or placed in shutdown. Otherwise, O.S. would remain active indefinitely for any event.

Figure 9. O.S. Output Temperature Response Diagram

TEMPERATURE DATA FORMAT

Temperature data can be read from the Temperature, T_{OS} Set Point, and T_{HYST} Set Point registers; and written to the T_{OS} Set Point, and T_{HYST} Set Point registers. Temperature data is represented by a 9-bit, two's complement word with an LSB (Least Significant Bit) equal to 0.5°C:

Tomporeture	Digital Output						
Temperature	Binary	Hex					
+125°C	0 1111 1010	0FAh					
+25°C	0 0011 0010	032h					
+0.5°C	0 0000 0001	001h					
0°C	0 0000 0000	000h					
−0.5°C	1 1111 1111	1FFh					
−25°C	1 1100 1110	1CEh					
-55°C	1 1001 0010	192h					

SHUTDOWN MODE

Shutdown mode is enabled by setting the shutdown bit in the Configuration register via the I^2C bus. Shutdown mode reduces power supply current significantly. See specified quiescent current specification in the Temperature-to-Digital Converter Characteristics table. In Interrupt mode O.S. is reset if previously set and is undefined in Comparator mode during shutdown. The I^2C interface remains active. Activity on the clock and data lines of the I^2C bus may slightly increase shutdown mode quiescent current. T_{OS} , T_{HYST} , and Configuration registers can be read from and written to in shutdown mode.

For the LM75B, the TIMEOUT feature is turned off in Shutdown Mode.

FAULT QUEUE

A fault queue of up to 6 faults is provided to prevent false tripping of O.S. when the LM75 is used in noisy environments. The number of faults set in the queue must occur consecutively to set the O.S. output.

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COMPARATOR/INTERRUPT MODE

As indicated in the O.S. Output Temperature Response Diagram, Figure 9, the events that trigger O.S. are identical for either Comparator or Interrupt mode. The most important difference is that in Interrupt mode the O.S. will remain set indefinitely once it has been set. To reset O.S. while in Interrupt mode, perform a read from any register in the LM75.

O.S. OUTPUT

The O.S. output is an open-drain output and does not have an internal pull-up. A "high" level will not be observed on this pin until pull-up current is provided from some external source, typically a pull-up resistor. Choice of resistor value depends on many system factors but, in general, the pull-up resistor should be as large as possible. This will minimize any errors due to internal heating of the LM75. The maximum resistance of the pull up, based on LM75 specification for High Level Output Current, to provide a 2V high level, is 30 k Ω .

O.S. POLARITY

The O.S. output can be programmed via the configuration register to be either active low (default mode), or active high. In active low mode the O.S. output goes low when triggered exactly as shown on the O.S. Output Temperature Response Diagram, Figure 9. Active high simply inverts the polarity of the O.S. output.

INTERNAL REGISTER STRUCTURE

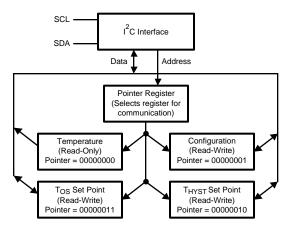


Figure 10.

There are four data registers in the LM75B and LM75C selected by the Pointer register. At power-up the Pointer is set to "000"; the location for the Temperature Register. The Pointer register latches whatever the last location it was set to. In Interrupt Mode, a read from the LM75, or placing the device in shutdown mode, resets the O.S. output. All registers are read and write, except the Temperature register which is a read only.

A write to the LM75 will always include the address byte and the Pointer byte. A write to the Configuration register requires one data byte, and the T_{OS} and T_{HYST} registers require two data bytes.

Reading the LM75 can take place either of two ways: If the location latched in the Pointer is correct (most of the time it is expected that the Pointer will point to the Temperature register because it will be the data most frequently read from the LM75), then the read can simply consist of an address byte, followed by retrieving the corresponding number of data bytes. If the Pointer needs to be set, then an address byte, pointer byte, repeat start, and another address byte will accomplish a read.

The first data byte is the most significant byte with most significant bit first, permitting only as much data as necessary to be read to determine temperature condition. For instance, if the first four bits of the temperature data indicates an overtemperature condition, the host processor could immediately take action to remedy the excessive temperatures. At the end of a read, the LM75 can accept either Acknowledge or No Acknowledge from the Master (No Acknowledge is typically used as a signal for the slave that the Master has read its last byte).



An inadvertent 8-bit read from a 16-bit register, with the D7 bit low, can cause the LM75 to stop in a state where the SDA line is held low as shown in Figure 11. This can prevent any further bus communication until at least 9 additional clock cycles have occurred. Alternatively, the master can issue clock cycles until SDA goes high, at which time issuing a "Stop" condition will reset the LM75.

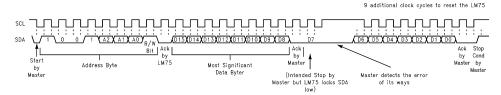


Figure 11. Inadvertent 8-Bit Read from 16-Bit Register where D7 is Zero ("0")

POINTER REGISTER (Selects which registers will be read from or written to):

P7	P6	P5	P4	P3	P2	P1	P0	
0	0	0	0	0	Register Select			

P0-P1: Register Select:

P2	P1	P0	Register
0	0	0	Temperature (Read only) (Power-up default)
0	0	1	Configuration (Read/Write)
0	1	0	T _{HYST} (Read/Write)
0	1	1	T _{OS} (Read/Write)

P3-P7: Must be kept zero.

TEMPERATURE REGISTER (Read Only):

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
MSB	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	LSB	Χ	Х	X	Х	X	X	Х

D0–D6: Undefined. D7–D15: Temperature Data. One LSB = 0.5°C. Two's complement format.

CONFIGURATION REGISTER (Read/Write):

D7	D6	D5	D4 D3		D2	D1	D0
0	0	0	Fault Queue		O.S. Polarity	Cmp/Int	Shutdown

Power up default is with all bits "0" (zero).

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D0: Shutdown: When set to 1 the LM75 goes to low power shutdown mode.

D1: Comparator/Interrupt mode: 0 is Comparator mode, 1 is Interrupt mode.

D2: O.S. Polarity: 0 is active low, 1 is active high. O.S. is an open-drain output under all conditions.

D3-D4: Fault Queue: Number of faults necessary to detect before setting O.S. output to avoid false tripping due to noise. Faults are determind at the end of a conversion. See specified temperature conversion time in the Temperature-to-Digital Converter Characteristics table.

D4	D3	Number of Faults					
0	0	1 (Power-up default)					
0	1	2					
1	0	4					
1	1	6					



D5-D7: These bits are used for production testing and must be kept zero for normal operation.

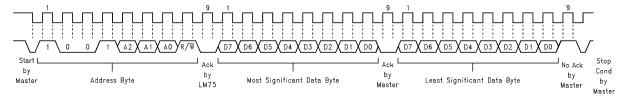
T_{HYST} AND T_{os} REGISTER (Read/Write):

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
MSB	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	LSB	Χ	Χ	X	X	X	Χ	X

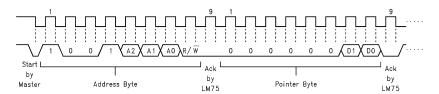
D0–D6: Undefined 75°C

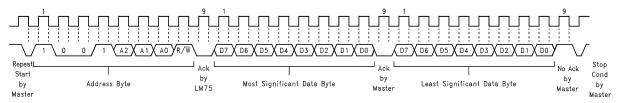
D7–D15: T_{HYST} Or T_{OS} Trip Temperature Data. Power up default is T_{OS} = 80°C, T_{HYST} =

TEST CIRCUIT DIAGRAMS

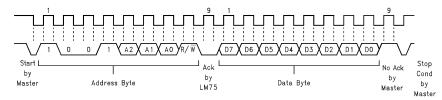


(a) Typical 2-Byte Read From Preset Pointer Location Such as Temp, T_{OS} , T_{HYST}





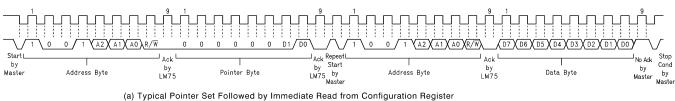
(b) Typical Pointer Set Followed by Immediate Read for 2-Byte Register such as Temp, T_{OS}, T_{HYST}



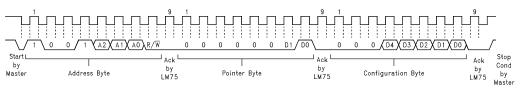
(c) Typical 1-Byte Read From Configuration Register With Preset Pointer

Figure 12.

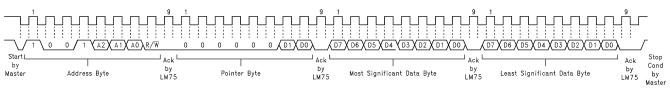




(a) Typical Pointer Set Followed by Immediate Read from Configuration Register



(b) Configuration Register Write



(c) T_{OS} and T_{HYST} Write

Figure 13. I²C Timing Diagrams (Continued)

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APPLICATION HINTS

To get the expected results when measuring temperature with an integrated circuit temperature sensor like the LM75, it is important to understand that the sensor measures its own die temperature. For the LM75, the best thermal path between the die and the outside world is through the LM75's pins. In the VSSOP package for the LM75B and LM75C, the GND pin is directly connected to the die, so the GND pin provides the best thermal path. If the other pins are at different temperatures (unlikely, but possible), they will affect the die temperature, but not as strongly as the GND pin. In the SOIC package, none of the pins is directly connected to the die, so they will all contribute similarly to the die temperature. Because the pins represent a good thermal path to the LM75 die, the LM75 will provide an accurate measurement of the temperature of the printed circuit board on which it is mounted. There is a less efficient thermal path between the plastic package and the LM75 die. If the ambient air temperature is significantly different from the printed circuit board temperature, it will have a small effect on the measured temperature.

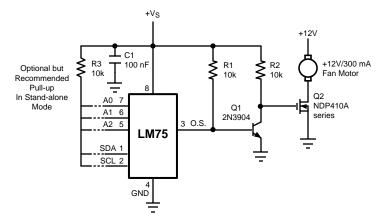
In probe-type applications, the LM75 can be mounted inside a sealed-end metal tube, and can then be dipped into a bath or screwed into a threaded hole in a tank. As with any IC, the LM75 and accompanying wiring and circuits must be kept insulated and dry, to avoid leakage and corrosion. This is especially true if the circuit may operate at cold temperatures where condensation can occur. Printed-circuit coatings and varnishes such as Humiseal and epoxy paints or dips are often used to insure that moisture cannot corrode the LM75 or its connections.

DIGITAL NOISE ISSUES

The LM75B features an integrated low-pass filter on both the SCL and the SDA digital lines to mitigate the effects of bus noise. Although this filtering makes the LM75B communication robust in noisy environments, good layout practices are always recommended. Minimize noise coupling by keeping digital traces away from switching power supplies. Also, ensure that digital lines containing high-speed data communications cross at right angles to the SDA and SCL lines.

Excessive noise coupling into the SDA and SCL lines on the LM75C-specifically noise with amplitude greater than 400 mV $_{pp}$ (the LM75's typical hysteresis), overshoot greater than 300 mV above $_{t}$ V $_{s}$, and undershoot more than 300 mV below GND-may prevent successful serial communication with the LM75C. Serial bus no-acknowledge is the most common symptom, causing unnecessary traffic on the bus. The layout procedures mentioned above apply also to the LM75C. Although the serial bus maximum frequency of communication is only 400 kHz, care must be taken to ensure proper termination within a system with long printed circuit board traces or multiple parts on the bus. Resistance can be added in series with the SDA and SCL lines to further help filter noise and ringing. A 5 k Ω resistor should be placed in series with the SCL line, placed as close as possible to the SCL pin on the LM75C. This 5 k Ω resistor, with the 5 pF to 10 pF stray capacitance of the LM75 provides a 6 MHz to 12 MHz low pass filter, which is sufficient filtering in most cases.

TYPICAL APPLICATIONS



When using the two-wire interface: program O.S. for active high and connect O.S. directly to Q2's gate.

Figure 14. Simple Fan Controller, Interface Optional



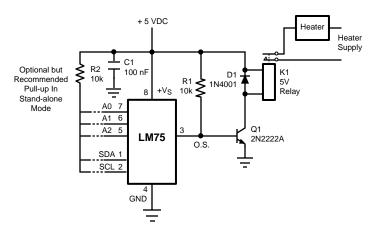


Figure 15. Simple Thermostat, Interface Optional

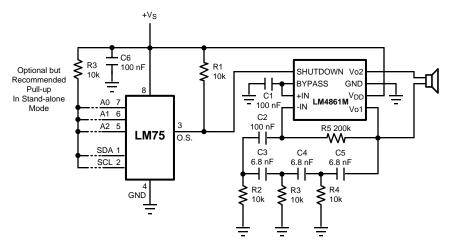


Figure 16. Temperature Sensor with Loudmouth Alarm (Barking Watchdog)

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REVISION HISTORY

Changes from Revision A (March 2013) to Revision B					
•	Changed layout of National Data Sheet to TI format		15		

Submit Documentation Feedback





11-Apr-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
LM75BIM-3	ACTIVE	SOIC	D	8	95	TBD	Call TI	Call TI	-55 to 125	LM75 BIM-3	Samples
LM75BIM-3/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-55 to 125	LM75 BIM-3	Samples
LM75BIM-5	ACTIVE	SOIC	D	8	95	TBD	Call TI	Call TI	-55 to 125	LM75 BIM-5	Samples
LM75BIM-5/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-55 to 125	LM75 BIM-5	Samples
LM75BIMM-3	ACTIVE	VSSOP	DGK	8	1000	TBD	Call TI	Call TI	-55 to 125	T01B	Samples
LM75BIMM-3/NOPB	ACTIVE	VSSOP	DGK	8	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-55 to 125	T01B	Samples
LM75BIMM-5	ACTIVE	VSSOP	DGK	8	1000	TBD	Call TI	Call TI	-55 to 125	T00B	Samples
LM75BIMM-5/NOPB	ACTIVE	VSSOP	DGK	8	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-55 to 125	T00B	Samples
LM75BIMMX-3	ACTIVE	VSSOP	DGK	8	3500	TBD	Call TI	Call TI	-55 to 125	T01B	Samples
LM75BIMMX-3/NOPB	ACTIVE	VSSOP	DGK	8	3500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-55 to 125	T01B	Samples
LM75BIMMX-5	ACTIVE	VSSOP	DGK	8	3500	TBD	Call TI	Call TI	-55 to 125	T00B	Samples
LM75BIMMX-5/NOPB	ACTIVE	VSSOP	DGK	8	3500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-55 to 125	T00B	Samples
LM75BIMX-3	ACTIVE	SOIC	D	8	2500	TBD	Call TI	Call TI	-55 to 125	LM75 BIM-3	Samples
LM75BIMX-3/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-55 to 125	LM75 BIM-3	Samples
LM75BIMX-5	ACTIVE	SOIC	D	8	2500	TBD	Call TI	Call TI	-55 to 125	LM75 BIM-5	Samples
LM75BIMX-5/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-55 to 125	LM75 BIM-5	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.



PACKAGE OPTION ADDENDUM

11-Apr-2013

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM75BIMM-3	VSSOP	DGK	8	1000	178.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM75BIMM-3/NOPB	VSSOP	DGK	8	1000	178.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM75BIMM-5	VSSOP	DGK	8	1000	178.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM75BIMM-5/NOPB	VSSOP	DGK	8	1000	178.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM75BIMMX-3	VSSOP	DGK	8	3500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM75BIMMX-3/NOPB	VSSOP	DGK	8	3500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM75BIMMX-5	VSSOP	DGK	8	3500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM75BIMMX-5/NOPB	VSSOP	DGK	8	3500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM75BIMX-3	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM75BIMX-3/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM75BIMX-5	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM75BIMX-5/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM75BIMM-3	VSSOP	DGK	8	1000	210.0	185.0	35.0
LM75BIMM-3/NOPB	VSSOP	DGK	8	1000	210.0	185.0	35.0
LM75BIMM-5	VSSOP	DGK	8	1000	210.0	185.0	35.0
LM75BIMM-5/NOPB	VSSOP	DGK	8	1000	210.0	185.0	35.0
LM75BIMMX-3	VSSOP	DGK	8	3500	367.0	367.0	35.0
LM75BIMMX-3/NOPB	VSSOP	DGK	8	3500	367.0	367.0	35.0
LM75BIMMX-5	VSSOP	DGK	8	3500	367.0	367.0	35.0
LM75BIMMX-5/NOPB	VSSOP	DGK	8	3500	367.0	367.0	35.0
LM75BIMX-3	SOIC	D	8	2500	367.0	367.0	35.0
LM75BIMX-3/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM75BIMX-5	SOIC	D	8	2500	367.0	367.0	35.0
LM75BIMX-5/NOPB	SOIC	D	8	2500	367.0	367.0	35.0

DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



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